Quad 2-Input Multiplexer with 3-State Outputs

The LSTTL/MSI SN74LS257B and the SN74LS258B are Quad 2-Input Multiplexers with 3-state outputs. Four bits of data from two sources can be selected using a Common Data Select input. The four outputs present the selected data in true (non-inverted) form. The outputs may be switched to a high impedance state with a HIGH on the common Output Enable (E_O) Input, allowing the outputs to interface directly with bus oriented systems. It is fabricated with the Schottky barrier diode process for high speed and is completely compatible with all ON Semiconductor TTL families.

- Schottky Process For High Speed
- Multiplexer Expansion By Tying Outputs Together
- Non-Inverting 3-State Outputs
- Input Clamp Diodes Limit High Speed Termination Effects
- Special Circuitry Ensures Glitch Free Multiplexing
- ESD > 3500 Volts

GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Мах	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current – High			-2.6	mA
I _{OL}	Output Current – Low			24	mA



ON Semiconductor Formerly a Division of Motorola

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LOW POWER SCHOTTKY



N SUFFIX CASE 648



ORDERING INFORMATION

Device	Package	Shipping
SN74LS257BN	16 Pin DIP	2000 Units/Box
SN74LS257BD	16 Pin	2500/Tape & Reel
SN74LS258BN	16 Pin DIP	2000 Units/Box
SN74LS258BD	16 Pin	2500/Tape & Reel

CONNECTION DIAGRAM DIP (TOP VIEW)



LOGIC DIAGRAMS



FUNCTIONAL DESCRIPTION

The LS257B and LS258B are Quad 2-Input Multiplexers with 3-state outputs. They select four bits of data from two sources each under control of a Common Data Select Input. When the Select Input is LOW, the I₀ inputs are selected and when Select is HIGH, the I₁ inputs are selected. The data on the selected inputs appears at the outputs in true (non-inverted) form for the LS257B and in the inverted form for the LS258B.

The LS257B and LS258B are the logic implementation of a 4-pole, 2-position switch where the position of the switch is determined by the logic levels supplied to the Select Input. The logic equations for the outputs are shown below:

LS257B

 $\begin{array}{l} Z_a = \overline{E}_0 \bullet (I_{1a} \bullet S + I_{0a} \bullet \overline{S}) \ Z_b = \overline{E}_0 \bullet (I_{1b} \bullet S + I_{0b} \bullet \overline{S}) \\ \overline{Z}_c = \overline{E}_0 \bullet (I_{1c} \bullet S + I_{0c} \bullet \overline{S}) \ \overline{Z}_d = \overline{E}_0 \bullet (I_{1d} \bullet S + I_{0d} \bullet \overline{S}) \end{array}$

When the Output Enable Input (\overline{E}_0) is HIGH, the outputs are forced to a high impedance "off" state. If the outputs are tied together, all but one device must be in the high impedance state to avoid high currents that would exceed the maximum ratings. Designers should ensure that Output Enable signals to 3-state devices whose outputs are tied together are designed so there is no overlap.

LS258B

Z _a =	$\overline{E}_0 \bullet$	(I _{1a}	• 5	; +	I_{0a}	•	S)	$\overline{Z}_{b} =$	\overline{E}_0	•	$(I_{1b}$	•	S	+	I_{0b}	•	S)
								$\overline{Z}_d =$									

TRUTH TABLE	
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OUTPUT ENABLE	SELECT INPUT	DATA INPUTS				OUTPUTS LS257B	OUTPUTS LS258B
Ēo	S	I ₀	I ₁	Z	Z		
Н	Х	Х	Х	(Z)	(Z)		
L	н	Х	L	L	н		
L	н	Х	Н	н	L		
L	L	L	Х	L	н		
L	L	Н	Х	Н	L		

H = HIGH Voltage Level

L = LOW Voltage Level X = Don't Care

(Z) = High Impedance (off)

			Limits						
Symbol	Parameter	Parameter		Тур	Max	Unit	Tes	t Conditions	
V _{IH}	Input HIGH Voltage		2.0			V	Guaranteed Input HIGH Voltage for All Inputs		
V _{IL}	Input LOW Voltage				0.8	V	Guaranteed Inpu All Inputs	t LOW Voltage for	
V _{IK}	Input Clamp Diode Voltage			-0.65	-1.5	V	$V_{CC} = MIN, I_{IN} =$	–18 mA	
V _{OH}	Output HIGH Voltage		2.4	3.1		V	V _{CC} = MIN, I _{OH} = or V _{IL} per Truth T		
M				0.25	0.4	V	I _{OL} = 12 mA	$V_{CC} = V_{CC} MIN,$ $V_{IN} = V_{IL} \text{ or } V_{IH}$	
V _{OL}	Output LOW Voltage			0.35	0.5	V	I _{OL} = 24 mA	$v_{IN} = v_{IL} \text{ or } v_{IH}$ per Truth Table	
I _{OZH}	Output Off Current — HIGH	ł			20	μΑ	V _{CC} = MAX, V _{OUT} = 2.7 V		
I _{OZL}	Output Off Current — LOW	1			-20	μΑ	$V_{CC} = MAX, V_{OUT} = 0.4 V$		
IIH	Input HIGH Current Other Inputs S Inputs				20 40	μΑ	V _{CC} = MAX, V _{IN} = 2.7 V		
	Other Inputs S Inputs				0.1 0.2	mA	V _{CC} = MAX, V _{IN}	= 7.0 V	
IIL	Input LOW Current All Inputs				-0.4	mA	$V_{CC} = MAX, V_{IN} = 0.4 V$		
I _{OS}	Short Circuit Current (Note	1)	-30		-130	mA	V _{CC} = MAX		
	Power Supply Current Total, Output HIGH	LS257B LS258B			10 9.0	mA			
I _{CC}	Total, Output LOW LS257B LS258B				16 14	mA	V _{CC} = MAX		
	Total, Output 3-State	LS257B LS258B			19 16	mA			

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Note 1: Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS (T_A = 25°C, V_{CC} = 5.0 V) See SN74LS251 for Waveforms

		Limits						
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions		
t _{PLH} t _{PHL}	Propagation Delay, Data to Output		10 12	13 15	ns	Figures 1 & 2	0 – 45 pE	
t _{PLH} t _{PHL}	Propagation Delay, Select to Output		14 14	21 21	ns	Figures 1 & 2	C _L = 45 pF	
t _{PZH}	Output Enable Time to HIGH Level		20	25	ns	Figures 4 & 5	C _L = 45 pF	
t _{PZL}	Output Enable Time to LOW Level		20	25	ns	Figures 3 & 5	R _L = 667 Ω	
t _{PLZ}	Output Disable Time to LOW Level		16	25	ns	Figures 3 & 5	C _L = 5.0 pF	
t _{PHZ}	Output Disable Time from HIGH Level		18	25	ns	Figures 4 & 5	R _L = 667 Ω	

PACKAGE DIMENSIONS



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL. 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH. 5. ROUNDED CORNERS OPTIONAL.

	INC	HES	MILLIN	ETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.740	0.770	18.80	19.55	
В	0.250	0.270	6.35	6.85	
С	0.145	0.175	3.69	4.44	
D	0.015	0.021	0.39	0.53	
F	0.040	0.70	1.02	1.77	
G	0.100	BSC	2.54 BSC		
Н	0.050	BSC	1.27 BSC		
J	0.008	0.015	0.21	0.38	
К	0.110	0.130	2.80	3.30	
L	0.295	0.305	7.50	7.74	
Μ	0°	10 °	0 °	10 °	
S	0.020	0.040	0.51	1.01	

PACKAGE DIMENSIONS



NOTES:

- NOTES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	9.80	10.00	0.386	0.393	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.054	0.068	
D	0.35	0.49	0.014	0.019	
F	0.40	1.25	0.016	0.049	
G	1.27	BSC	0.050	BSC	
J	0.19	0.25	0.008	0.009	
К	0.10	0.25	0.004	0.009	
Μ	0 °	7°	0 °	7°	
Р	5.80	6.20	0.229	0.244	
R	0.25	0.50	0.010	0.019	

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